Thyristor Semiconductor Device - Page 1 of 1



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	closure Material:
Pla	astic
٥v	rerall Length:
Be	tween 0.225 inches and 0.265 inches
Те	rminal Length:
0.5	500 inches
Ov	verall Diameter:
Be	tween 0.195 inches and 0.205 inches
Int	ernal Configuration:
Un	ijunction
Ele	ectrode Internally-electrically Connected To Case:
An	ode
Mo	ounting Method:
Те	rminal
Fe	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sil	icon
Vo	Itage Rating In Volts Per Characteristic:
1.5	on voltage, forward voltage drop, dc and 1.5 on-state voltage, dc
Cu	Irrent Rating Per Characteristic:
5.0	00 microamperes source cutoff current pascal and 50.00 milliamperes forward current, total rms nanoamperes and 2.00 amperes forward
cu	rrent, total rms torr
Sp	ecial Features:
Ju	nction pattern arrangement: pnpn
Те	rminal Type And Quantity:
3ι	ininsulated wire lead
Sp	ecification Data:
80	131-release6210 professional/industrial association specification
Sh	elf Life:
N/a	a
Un	it Of Measure:
De	militarization:
No	
Fii	g:
	10a0